## NSN 5961-01-328-9040

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-328-9040 **Inclosure Material:** Glass **Overall Length:** 0.280 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.250 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 4.00 amperes forward current, average absolute and 1.00 milliamperes forward current, average peak **Test Data Document:** 07187-8507001 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) and 07187-8509312 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No